LM4041 **Precision Micropower Shunt Voltage Reference**

General Description

Ideal for space critical applications, the LM4041 precision voltage reference is available in the sub-miniature (3 mm x 1.3 mm) SOT-23 surface-mount package. The LM4041's advanced design eliminates the need for an external stabilizing capacitor while ensuring stability with any capacitive load, thus making the LM4041 easy to use. Further reducing design effort is the availability of a fixed (1.225V) and adjustable reverse breakdown voltage. The minimum operating current is 60 μ A for the LM4041-1.2 and the LM4041-ADJ. Both versions have a maximum operating current of 12 mA.

The LM4041 utilizes fuse and zener-zap reverse breakdown or reference voltage trim during wafer sort to ensure that the prime parts have an accuracy of better than $\pm 0.1\%$ (A grade) at 25°C. Bandgap reference temperature drift curvature correction and low dynamic impedance ensure stable reverse breakdown voltage accuracy over a wide range of operating temperatures and currents.

Features

- Small packages: SOT-23, TO-92, and SO-8
- No output capacitor required
- Tolerates capacitive loads

- Reverse breakdown voltage options of 1.225V and adjustable
- Contact National Semiconductor Analog Marketing for parts with extended temperature range

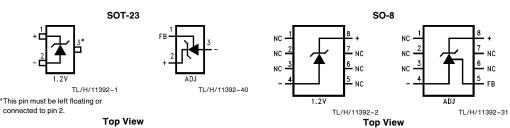
Key Specifications (LM4041-1.2)

- Output voltage tolerance (A grade, 25°C) ±0.1% (max)
- Low output noise (10 Hz to 10 kHz) 20 μ V_{rms} (typ)
- Wide operating current range
- 60 μA to 12 mA ■ Industrial temperature range -40°C to +85°C
- 100 ppm/°C (max) ■ Low temperature coefficient

Applications

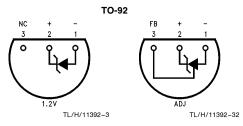
- Portable, Battery-Powered Equipment
- Data Acquisition Systems
- Instrumentation
- **Process Control**
- Energy Management
- Product Testing
- Automotive
- Precision Audio Components

Connection Diagrams



See NS Package Number M03B (JEDEC Registration TO-236AB)

See NS Package Number M08A



Bottom View See NS Package Number Z03A

Reverse Breakdown Voltage Tolerance at 25°C and Average Reverse Breakdown Voltage Temperature Coefficient	Package					
	M3 (SOT-23)	Z (TO-92)	M (SO-8)			
±0.1%, 100 ppm/°C max (A grade)	LM4041AIM3-1.2	LM4041AIZ-1.2	LM4041AIM-1.2			
	See NS Package	See NS Package	See NS Package			
	Number M03B	Number Z03A	Number M08A			
±0.2%, 100 ppm/°C max (B grade)	LM4041BIM3-1.2	LM4041BIZ-1.2	LM4041BIM-1.2			
	See NS Package	See NS Package	See NS Package			
	Number M03B	Number Z03A	Number M08A			
±0.5%, 100 ppm/°C max (C grade)	LM4041CIM3-1.2	LM4041CIZ-1.2,	LM4041CIM-1.2,			
	LM4041CIM3-ADJ	LM4041CIZ-ADJ	LM4041CIM-ADJ			
	See NS Package	See NS Package	See NS Package			
	Number M03B	Number Z03A	Number M08A			
±1.0%, 150 ppm/°C max (D grade)	LM4041DIM3-1.2	LM4041DIZ-1.2,	LM4041DIM-1.2,			
	LM4041DIM3-ADJ	LM4041DIZ-ADJ	LM4041DIM-ADJ			
	See NS Package	See NS Package	See NS Package			
	Number M03B	Number Z03A	Number M08A			
\pm 2.0%, 150 ppm/°C max (E grade)	LM4041EIM3-1.2	LM4041EIZ-1.2				

SOT-23 Package Marking InformationOnly three fields of marking are possible on the SOT-23's small surface. This table gives the meaning of the three fields.

Part Marking	Field Definition			
R1A	First Field:			
R1B	R = Reference			
R1C	Second Field:			
R1D	1 = 1.225V Voltage Option			
R1E	A = Adjustable			
	Third Field:			
RAC	A-E = Initial Reverse Breakdown			
RAD	Voltage or Reference Voltage Tolerance			
ПАР	$A = \pm 0.1\%, B = \pm 0.2\%, C = \pm 0.5\%, D = \pm 1.0\%, E = \pm 2.0\%$			

Absolute Maximum Ratings (Note 1)

If Military/Aerospace specified devices are required, please contact the National Semiconductor Sales Office/Distributors for availability and specifications.

Reverse Current 20 mA Forward Current 10 mA Maximum Output Voltage (LM4041-ADJ) 15V

Power Dissipation ($T_A = 25^{\circ}C$) (Note 2) M Package 540 mW M3 Package 306 mW Z Package 550 mW Storage Temperature -65° C to $+150^{\circ}$ C

Lead Temperature

M and M3 Packages Vapor phase (60 seconds) +215°C Infrared (15 seconds) +220°C Z Package

Soldering (10 seconds)

+260°C

ESD Susceptibility

Human Body Model (Note 3) 2 kV Machine Model (Note 3) 200V

See AN-450 "Surface Mounting Methods and Their Effect on Product Reliability" for other methods of soldering surface mount devices.

Operating Ratings (Notes 1 & 2)

Temperature Range

 $(T_{min} \leq T_A \leq T_{max})$ $-40^{\circ}C \leq T_{A} \leq +85^{\circ}C$

Reverse Current

LM4041-1.2 60 μ A to 12 mA LM4041-ADJ 60 μA to 12 mA

Output Voltage Range

LM4041-ADJ 1.24V to 10V

LM4041-1.2

Electrical Characteristics

Boldface limits apply for T_A = **T**_J = **T_{MIN} to T_{MAX}**; all other limits T_A = T_J = 25°C. The grades A and B designate initial Reverse Breakdown Voltage tolerances of $\pm 0.1\%$ and $\pm 0.2\%$, respectively.

Symbol	Parameter	Conditions	Typical (Note 4)	LM4041AIM LM4041AIM3 LM4041AIZ Limits (Note 5)	LM4041BIM LM4041BIM3 LM4041BIZ Limits (Note 5)	Units (Limit)
V _R	Reverse Breakdown Voltage	I _R = 100 μA	1.225			V
	Reverse Breakdown Voltage Tolerance (Note 6)	I _R = 100 μA		± 1.2 ± 9.2	±2.4 ± 10.4	mV (max) mV (max)
I _{RMIN}	Minimum Operating Current		45	60 65	60 65	μΑ μΑ (max) μΑ (max)
$\Delta V_R/\Delta T$	Average Reverse Breakdown Voltage Temperature Coefficient	$I_R = 10 \text{ mA}$ $I_R = 1 \text{ mA}$ $I_R = 100 \mu \text{A}$	±20 ±15 ±15	± 100	± 100	ppm/°C ppm/°C (max) ppm/°C
$\Delta V_{R}/\Delta I_{R}$	Reverse Breakdown Voltage Change with Operating Current Change	$I_{RMIN} \le I_{R} \le 1 \text{ mA}$	0.7	1.5 2.0	1.5 2.0	mV mV (max) mV (max)
		1 mA \leq I _R \leq 12 mA	4.0	6.0 8.0	6.0 8.0	mV mV (max) mV (max)
Z _R	Reverse Dynamic Impedance	$I_R = 1 \text{ mA, } f = 120 \text{ Hz,}$ $I_{AC} = 0.1 I_R$	0.5	1.5	1.5	Ω Ω (max)
e _N	Wideband Noise	$I_R = 100 \mu A$ $10 \text{ Hz} \le \text{f} \le 10 \text{ kHz}$	20			μV _{rms}
ΔV _R	Reverse Breakdown Voltage Long Term Stability	t = 1000 hrs $T = 25^{\circ}\text{C} \pm 0.1^{\circ}\text{C}$ $I_{\text{R}} = 100 \mu\text{A}$	120			ppm

LM4041-1.2 (Continued)

Electrical Characteristics (Continued)

Boldface limits apply for T_A = **T**_J = **T_{MIN} to T_{MAX}**; all other limits $T_A = T_J = 25^{\circ}C$. The grades C, D and E designate initial Reverse Breakdown Voltage tolerances of $\pm 0.5\%$, $\pm 1.0\%$ and $\pm 2.0\%$, respectively.

Symbol	Parameter	Conditions	Typical (Note 4)	I M4041CIZ	LM4041DIM LM4041DIM3 LM4041DIZ Limits (Note 5)	LM4041EIM3 LM4041EIZ Limits (Note 5)	Units (Limit)
V _R	Reverse Breakdown Voltage	$I_R = 100 \mu A$	1.225				V
	Reverse Breakdown Voltage Tolerance (Note 6)	$I_R = 100 \mu A$		±6 ±14	±12 ± 24	±25 ± 36	mV (max) mV (max)
I _{RMIN}	Minimum Operating Current		45	60 65	65 70	65 70	μΑ μΑ (max) μΑ (max)
ΔV _R /ΔT	Average Reverse Breakdown Voltage Temperature Coefficient	$I_R = 10 \text{ mA}$ $I_R = 1 \text{ mA}$ $I_R = 100 \mu \text{A}$	±20 ±15 ±15	± 100	± 150	± 150	ppm/°C ppm/°C (max) ppm/°C
$\Delta V_{R}/\Delta I_{R}$	Reverse Breakdown Voltage Change with Operating Current Change	$I_{RMIN} \le I_R \le 1 \text{ mA}$	0.7	1.5 2.0	2.0 25	2.0 2.5	mV mV (max) mV (max)
		1 mA \leq I _R \leq 12 mA	2.5	6.0 8.0	8.0 10.0	8.0 10.0	mV mV (max) mV (max)
Z _R	Reverse Dynamic Impedance	$I_R = 1 \text{ mA, f} = 120 \text{ Hz}$ $I_{AC} = 0.1 I_R$	0.5	1.5	2.0	2.0	Ω Ω (max)
e _N	Wideband Noise	$I_{\text{R}} = 100 \ \mu\text{A}$ $10 \ \text{Hz} \leq \text{f} \leq 10 \ \text{kHz}$	20				μV_{rms}
ΔV _R	Reverse Breakdown Voltage Long Term Stability	t = 1000 hrs $T = 25^{\circ}\text{C} \pm 0.1^{\circ}\text{C}$ $I_{R} = 100 \mu\text{A}$	120				ppm

LM4041-ADJ (Adjustable)

Electrical Characteristics Boldface limits apply for T_A = T_J = T_{MIN} to T_{MAX}; all other limits T_J = 25°C unless otherwise specified (SOT-23, see Note 7), I_{RMIN} \leq I_R \leq 12 mA, V_{REF} \leq V_{OUT} \leq 10V. The grades C and D designates initial Reference Voltage Tolerances of \pm 0.5% and \pm 1%, respectively for V_{OUT} = 5V.

Symbol	Parameter	Conditions	Typical (Note 4)	LM4041CIM LM4041CIM3 LM4041CIZ (Note 5)	LM4041DIM LM4041DIM3 LM4041DIZ (Note 5)	Units (Limit)
V _{REF}	Reference Voltage	$I_R = 100 \ \mu A, V_{OUT} = 5V$	1.233			V
	Reference Voltage Tolerance (Note 8)	$I_{R} = 100 \ \mu A, V_{OUT} = 5V$		±6.2 ± 14	±12 ± 24	mV (max) mV (max)
I _{RMIN}	Minimum Operating Current		45	60 65	65 70	μΑ μΑ (max) μΑ (max)

LM4041-ADJ (Adjustable) (Continued)

Electrical Characteristics (Continued)

Boldface limits apply for T_A = **T**_J = **T_{MIN} to T_{MAX}**; all other limits T_J = 25°C unless otherwise specified (SOT-23, see Note 7), $I_{RMIN} \le I_R \le 12$ mA, $V_{REF} \le V_{OUT} \le 10$ V. The grades C and D designates initial Reference Voltage Tolerances of $\pm 0.5\%$ and $\pm 1\%$, respectively for $V_{OUT} = 5$ V.

Symbol	Parameter	Conditions	Typical (Note 4)	LM4041CIM LM4041CIM3 LM4041CIZ (Note 5)	LM4041DIM LM4041DIM3 LM4041DIZ (Note 5)	Units (Limit)
$\Delta V_{REF}/\Delta I_{R}$	Reference Voltage Change with Operating Current Change	$\begin{split} &I_{RMIN} \leq I_{R} \leq 1 \text{ mA} \\ &SOT\text{-}23\text{: } V_{OUT} \geq 1.6V \text{ (Note 7)} \end{split}$	0.7	1.5 2.0	2.0 2.5	mV mV (max) mV (max)
		1 mA \leq I _R \leq 12 mA SOT-23: V _{OUT} \geq 1.6V (Note 7)	2	4	6 8	mV mV (max) mV (max)
$\Delta V_{REF}/\Delta V_{O}$	Reference Voltage Change with Output Voltage Change	I _R = 1 mA	-1.3	-2.0 - 2.5	-2.5 - 3.0	mV/V mV/V (max) mV/V (max)
I _{FB}	Feedback Current		60	100 120	150 200	nA nA (max) nA (max)
$\Delta V_{REF}/\Delta T$	Average Reference Voltage Temperature Coefficient (Note 8)	$V_{OUT}=5V,$ $I_{R}=10$ mA $I_{R}=1$ mA $I_{R}=100$ μ A	20 15 15	± 100	± 150	ppm/°C ppm/°C (max) ppm/°C
Z _{OUT}	Dynamic Output Impedance	$\begin{split} I_{R} = 1 \text{ mA, f} = 120 \text{ Hz,} \\ I_{AC} = 0.1 I_{R} \\ V_{OUT} = V_{REF} \\ V_{OUT} = 10V \end{split}$	0.3 2			$\Omega \Omega$
e _N	Wideband Noise	$\begin{split} I_R &= 100 \; \mu\text{A} V_{OUT} = V_{REF} \\ 10 \; Hz \leq f \leq 10 \; \text{kHz} \end{split}$	20			μV_{rms}
ΔV _{REF}	Reference Voltage Long Term Stability	$t=$ 1000 hrs, $I_R=$ 100 μA $T=$ 25°C \pm 0.1°C	120			ppm

Note 1: Absolute Maximum Ratings indicate limits beyond which damage to the device may occur. Operating Ratings indicate conditions for which the device is functional, but do not guarantee specific performance limits. For guaranteed specifications and test conditions, see the Electrical Characteristics. The guaranteed specifications apply only for the test conditions listed. Some performance characteristics may degrade when the device is not operated under the listed test conditions.

Note 2: The maximum power dissipation must be derated at elevated temperatures and is dictated by T_{Jmax} (maximum junction temperature), θ_{JA} (junction to ambient thermal resistance), and T_A (ambient temperature). The maximum allowable power dissipation at any temperature is $PD_{max} = (T_{Jmax} - T_A)/\theta_{JA}$ or the number given in the Absolute Maximum Ratings, whichever is lower. For the LM4041, $T_{Jmax} = 125^{\circ}C$, and the typical thermal resistance (θ_{JA}), when board mounted, is $185^{\circ}C/W$ for the M package, $326^{\circ}C/W$ for the SOT-23 package, and $180^{\circ}C/W$ with 0.4° lead length and $170^{\circ}C/W$ with 0.125° lead length for the T_{CO} 20 ackage.

Note 3: The human body model is a 100 pF capacitor discharged through a 1.5 kΩ resistor into each pin. The machine model is a 200 pF capacitor discharged directly into each pin.

Note 4: Typicals are at $T_J = 25^{\circ}C$ and represent most likely parametric norm.

Note 5: Limits are 100% production tested at 25°C. Limits over temperature are guaranteed through correlation using Statistical Quality Control (SQC) methods. The limits are used to calculate National's AOQL.

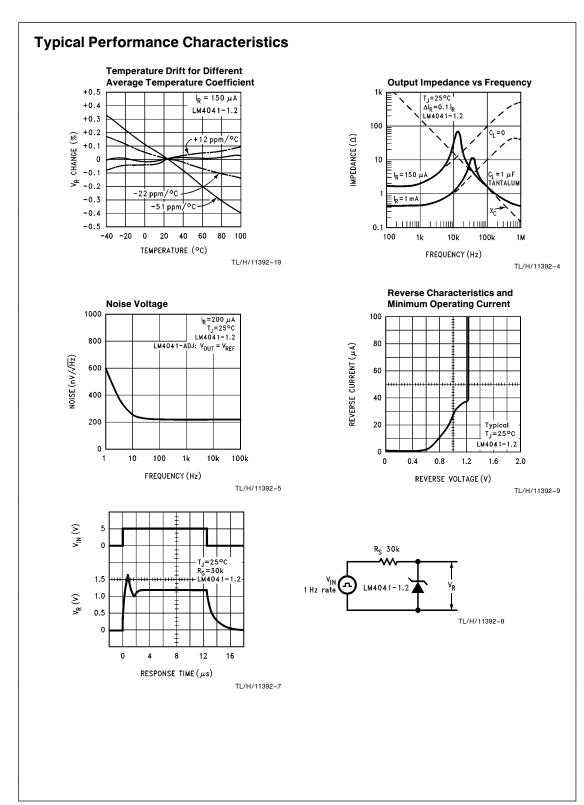
Note 6: The boldface (over-temperature) limit for Reverse Breakdown Voltage Tolerance is defined as the room temperature Reverse Breakdown Voltage Tolerance $\pm [(\Delta V_R/\Delta T)(65^{\circ}C)(V_R)]$. $\Delta V_R/\Delta T$ is the V_R temperature coefficient, 65°C is the temperature range from $-40^{\circ}C$ to the reference point of 25°C, and V_R is the reverse breakdown voltage. The total over-temperature tolerance for the different grades is shown below:

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A-grade: \pm 0.75\% = \pm 0.1\% \pm 100 \text{ ppm/°C} \times 65^{\circ}\text{C} B-grade: \pm 0.85\% = \pm 0.2\% \pm 100 \text{ ppm/°C} \times 65^{\circ}\text{C} C-grade: \pm 1.15\% = \pm 0.5\% \pm 100 \text{ ppm/°C} \times 65^{\circ}\text{C} D-grade: \pm 1.98\% = \pm 1.0\% \pm 150 \text{ ppm/°C} \times 65^{\circ}\text{C} E-grade: \pm 2.98\% = \pm 2.0\% \pm 150 \text{ ppm/°C} \times 65^{\circ}\text{C}
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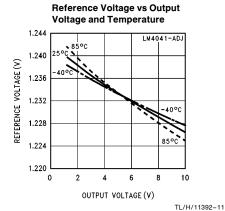
Therefore, as an example, the A-grade LM4041-1.2 has an over-temperature Reverse Breakdown Voltage tolerance of $\pm 1.2 \text{V} \times 0.75\% = \pm 9.2 \text{ mV}$.

Note 7. When $V_{OUT} \le$ 1.6V, the LM4041-ADJ in the SOT-23 package must operate at reduced I_R. This is caused by the series resistance of the die attach between the die (-) output and the package (-) output pin. See the Output Saturation (SOT-23 only) curve in the Typical Performance Characteristics section.

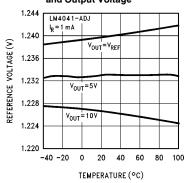
Note 8. Reference voltage and temperature coefficient will change with output voltage. See Typical Performance Characteristics curves.





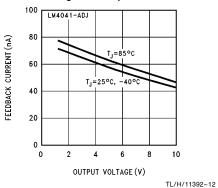


Reference Voltage vs Temperature and Output Voltage

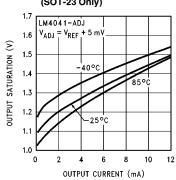


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Feedback Current vs Output Voltage and Temperature

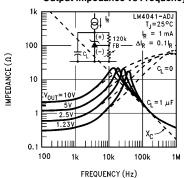


Output Saturation (SOT-23 Only)

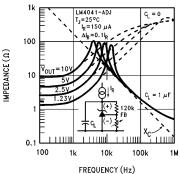


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Output Impedance vs Frequency

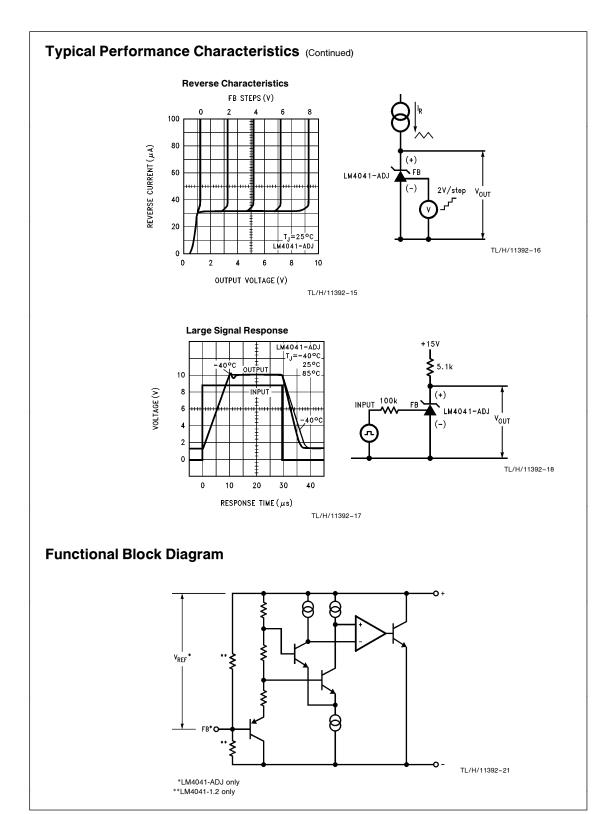


Output Impedance vs Frequency



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TL/H/11392-13



Applications Information

The LM4041 is a precision micro-power curvature-corrected bandgap shunt voltage reference. For space critical applications, the LM4041 is available in the sub-miniature SOT-23 surface-mount package. The LM4041 has been designed for stable operation without the need of an external capacitor connected between the "+" pin and the "-" pin. If, however, a bypass capacitor is used, the LM4041 remains stable. Design effort is further reduced with the choice of either a fixed 1.2V or an adjustable reverse breakdown voltage. The minimum operating current is 60 $\mu\rm{A}$ for the LM4041-1.2 and the LM4041-ADJ. Both versions have a maximum operating current of 12 mA.

LM4041s using the SOT-23 package have pin 1 connected as the (-) output through the package's die attach interface. Therefore, the LM4041-1.2's pin 1 must be left floating or connected to pin 3 and the LM4041-ADJ's pin 1 is the (-) output.

In a conventional shunt regulator application (Figure 1), an external series resistor (R_S) is connected between the supply voltage and the LM4041. R_S determines the current that flows through the load (I_L) and the LM4041 (I_Q). Since load current and supply voltage may vary, R_S should be small enough to supply at least the minimum acceptable I_Q to the LM4041 even when the supply voltage is at its minimum and the load current is at its maximum value. When the supply voltage is at its minimum, R_S should be large enough so that the current flowing through the LM4041 is less than 12 mA.

 R_S is determined by the supply voltage, (V_S), the load and operating current, (I_L and I_Q), and the LM4041's reverse breakdown voltage, V_R.

$$R_S = \frac{v_S - v_R}{I_L + I_Q}$$

The LM4041-ADJ's output voltage can be adjusted to any value in the range of 1.24V through 10V. It is a function of the internal reference voltage (V_{REF}) and the ratio of the external feedback resistors as shown in *Figure 2*. The output is found using the equation

$$V_{O} = V_{REF'} \left(\frac{R2}{R1} + 1 \right) \tag{1}$$

where V_O is the desired output voltage. The actual value of the internal V_{REF} is a function of V_O . The "corrected" V_{REF} is determined by

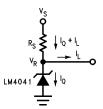
$$V_{REF}' = V_O (\Delta V_{REF}/\Delta V_O) + V_Y$$
 (2)

where V_O is the desired output voltage. $\Delta V_{REF}/\Delta V_O$ is found in the Electrical Characteristics and it typically -1.3 mV/V and V_Y is equal to 1.240V. Replace the value of V_{REF}' in equation (1) with the value found using equation (2).

Note that the actual output voltage can deviate from that predicted using the typical $\Delta V_{REF}/\Delta V_O$ in equation (2): for C-grade parts, the worst-case $\Delta V_{REF}/\Delta V_O$ is -2.5 mV/V and $V_Y=1.246V.$ For D-grade parts, the worst-case $\Delta V_{REF}/\Delta V_O$ is -3.0 mV/V and $V_Y=1.248V.$

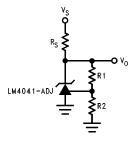
The following example shows the difference in output voltage resulting from the typical and worst case values of $\Delta V_{REF}/\Delta V_O$. Let $V_O=+9V$. Using the typical value of $\Delta V_{REF}/\Delta V_O$, V_{REF} is 1.228V. Choosing a value of R1 = 10 kΩ, R2 = 63.272 kΩ. Using the worst case $\Delta V_{REF}/\Delta V_O$ for the C-grade and D-grade parts, the output voltage is actually 8.965V and 8.946V, respectively. This results in possible errors as large as 0.39% for the C-grade parts and 0.59% for the D-grade parts. Once again, resistor values found using the typical value of $\Delta V_{REF}/\Delta V_O$ will work in most cases, requiring no further adjustment.

Typical Applications



TI /H/11392-22

FIGURE 1. Shunt Regulator



TI /H/11392-34

FIGURE 2. Adjustable Shunt Regulator

Typical Applications (Continued)

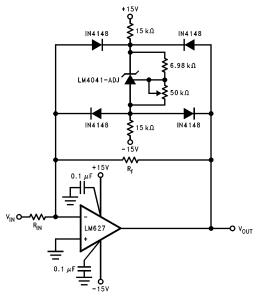


FIGURE 3. Bounded amplifier reduces saturation-induced delays and can prevent succeeding stage damage. Nominal clamping voltage is $\pm\,V_{O}$ (LM4041's reverse breakdown voltage) $+\,2$ diode $V_{F}.$

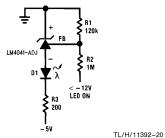
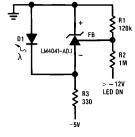


FIGURE 4. Voltage Level Detector



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FIGURE 5. Voltage Level Detector

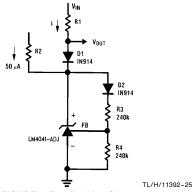


FIGURE 6. Fast Positive Clamp 2.4V $+ \Delta V_{D1}$

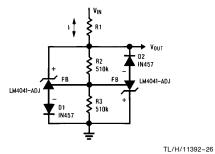
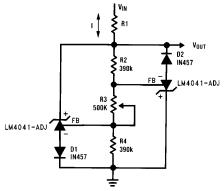


FIGURE 7. Bidirectional Clamp $\,\pm\,2.4V$

Typical Applications (Continued)



R2 330k D2 IN457

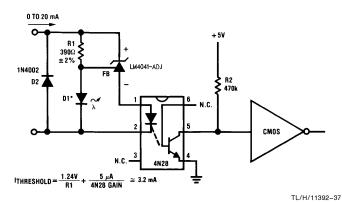
FB R3 IM FB LM4041-ADJ

D1 IN457 R4 330k

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FIGURE 7. Bidirectional Adjustable Clamp ± 18V to ± 2.4V

FIGURE 8. Bidirectional Adjustable Clamp $\pm \textbf{2.4V}$ to $\pm \textbf{6V}$



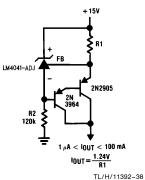


FIGURE 10. Current Source

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FIGURE 9. Simple Floating Current Detector

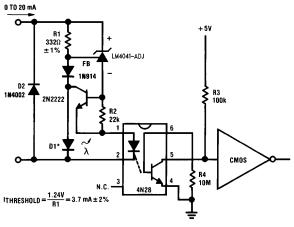
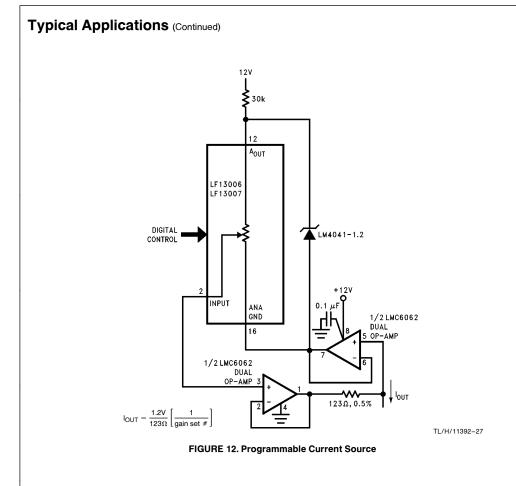


FIGURE 11. Precision Floating Current Detector

*D1 can be any LED, $V_F=1.5V$ to 2.2V at 3 mA. D1 may act as an indicator. D1 will be on if $I_{THRESHOLD}$ falls below the threshold current, except with I=O.



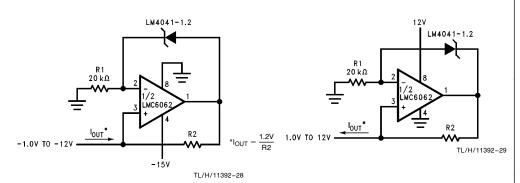
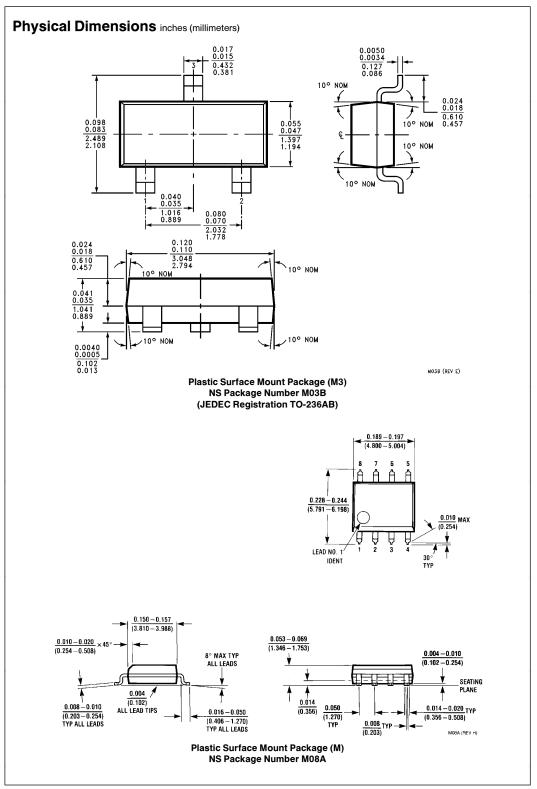
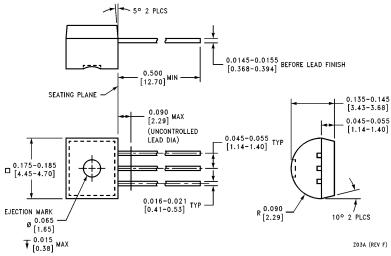


FIGURE 13. Precision 1 $\mu\mathrm{A}$ to 1 mA Current Sources



Physical Dimensions inches (millimeters) (Continued)



Plastic Package (Z) NS Package Number Z03A

LIFE SUPPORT POLICY

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- A critical component is any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.



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